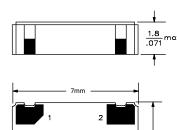


3.3V CMOS Low Jitter, High Frequency **Crystal Clock Oscillator (XO)**

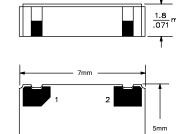




Packaging Outline



| Pin Functions | | |
|---------------|--------------------|--|
| Pin | Function | |
| 1 | OE Function | |
| 2 | Ground | |
| 3 | Clock Output | |
| 4 | VDD | |

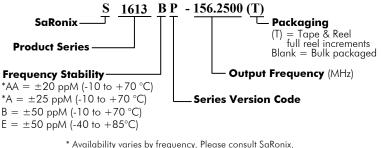


Common Frequencies

Contact SaRonix for additional frequencies

| 100.0000 MHz | 150.0000 MHz |
|--------------|--------------|
| 106.2500 MHz | 155.5200 MHz |
| 125.0000 MHz | 156.2500 MHz |
| 127.0000 MHz | 159.3750 MHz |
| 133.0000 MHz | |

Ordering Information



Actual Size $= 5 \times 7$ mm



Product Features

- Thicker crystal for improved reliability
- Less than 1 ps RMS jitter with advanced non-PLL, patent-pending design
- \pm 50ppM accuracy (all rated conditions including aging) standard for commercial or industrial operating conditions
- 3.3V CMOS/TTL compatible logic levels
- Pin-compatible with standard 5x7mm packages
- Designed for standard reflow and washing techniques
- IBIS model available •
- Pb-free and RoHS/Green compliant** ٠ (**per #7, Annex of Directive 2002/05/EC)

Product Description

The S1613XP Series is an enhanced high-frequency version of the popular \$1613 series, a 3.3V crystal clock oscillator that achieves superb jitter and stability over a broad range of operating conditions and frequencies. The output clock signal, generated internally with a non-PLL oscillator design, is compatible with LVCMOS/LVTTL logic levels. The device, available on tape and reel, is contained in a 5x7mm surface-mount ceramic package.

Applications

The S1613XP Series is an ideal reference clock for highspeed applications requiring low jitter, including:

- 1/10 Gigabit Ethernet
- FibreChannel •
- Serial Attached SCSI (SAS)
- Server & Storage platforms
- SONET/SDH linecards





3.3V CMOS Low Jitter, High Frequency Crystal Clock Oscillator (XO)

Electrical Performance

| Parameter | Min. | Тур. | Max. | Units | Notes |
|---------------------------------|-------------------------|------|------------------------|-----------------|---|
| Output frequency | 100 | | 160 | MHz | As specified |
| Supply voltage | +2.97 | +3.3 | +3.63 | V | |
| Supply current, output enabled | | | 30 | mA | |
| Supply current, output disabled | | | 10 | mA | Output Hi-Z |
| Frequency stability | | | ±20 to ±50 | ррМ | See Note 1 below |
| Operating temperature | -40 | | +85 | °C | As specified |
| Output logic 0, VOL | | | 10% V _{DD} | V | |
| Output logic 1, VOH | 90% V _{DD} | | | V | |
| Output load | 15 pF (max) or 10 LSTTL | | | TL | |
| Duty cycle | 45 | | 55 | % | -10 to +70°C measured 50%VDD |
| Duty cycle | 40 | | 60 | % | -40 to -10°C, +70 to +85°C measured 50%VDD |
| Rise and fall time | | | 2 | ns | measured 20/80% of waveform |
| Jitter, phase | | 0.25 | 1 | ps RMS (1-σ) | 12kHz to 40MHz frequency band |
| Jitter, accumulated | | | 7 | ps RMS (1-σ) | 20,000 adjacent periods |
| Jitter, total | | | 40 | ps pk-pk | 100,000 random periods |
| Subharmonic Level | | | -40 | dBc | |

Notes:

1. As specified. Stability includes all combinations of operating temperature, load changes, rated input (supply) voltage changes, initial calibration tolerance (25°C), aging (1 year at 25°C average effective ambient temperature), shock and vibration.

| Sulput Enable / Disable Function | | | | | |
|--|------|------|------|-------|----------------|
| Parameter | Min. | Тур. | Max. | Units | Notes |
| Input Voltage (pin 1), Output Enable | 2.2 | | | V | or open |
| Input voltage (pin 1), Output Disable | | | 0.8 | V | Output is Hi-Z |
| Internal pullup resistance | 50 | | | kΩ | |
| Output disable delay | | | 100 | ns | |
| Output enable delay | | | 1 | ms | |

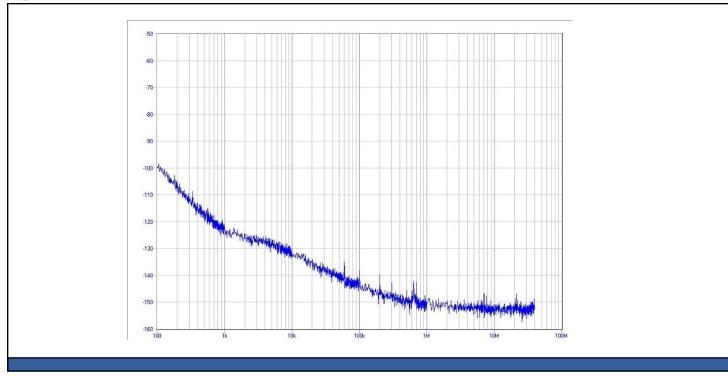
Output Enable / Disable Function



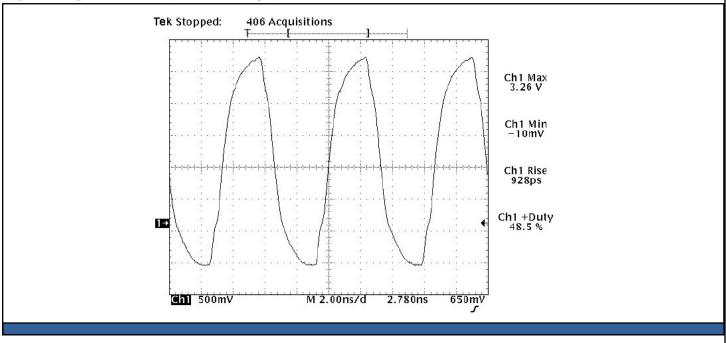


3.3V CMOS Low Jitter, High Frequency Crystal Clock Oscillator (XO)

Typical Phase Noise



Typical Output Waveform (150 MHz output)



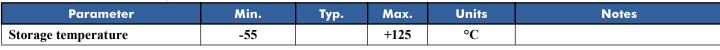
All specifications are subject to change without notice. DS 263 Rev B | 08/19/05



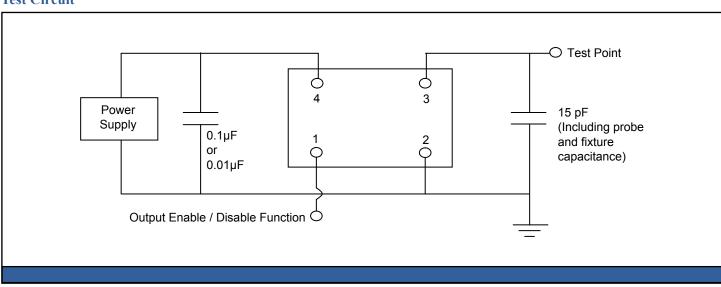


3.3V CMOS Low Jitter, High Frequency Crystal Clock Oscillator (XO)

Absolute Maximum Ratings



Test Circuit



Reliability Test Ratings

This product is rated to meet the following test conditions:

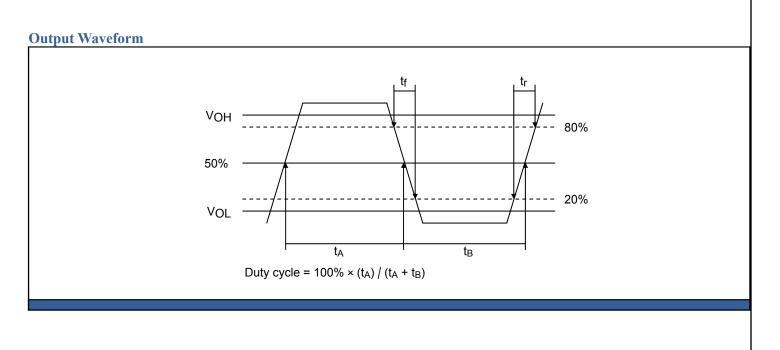
| Туре | Parameter | Test Condition |
|---------------|------------------------------|--|
| Mechanical | Shock | MIL-STD-883, Method 2002, Condition B |
| Mechanical | Solderability | JESD22-B102-D Method 2 (Preconditioning E) |
| Mechanical | Terminal strength | MIL-STD-883, Method 2004, Condition D |
| Mechanical | Gross leak | MIL-STD-883, Method 1014, Condition C |
| Mechanical | Fine leak | MIL-STD-883, Method 1014, Condition A2 ($R_1 = 2x10^{-8}$ atm cc/s) |
| Mechanical | Solvent resistance | MIL-STD-202, Method 215 |
| Environmental | Thermal shock | MIL-STD-883, Method 1011, Condition A |
| Environmental | Moisture resistance | MIL-STD-883, Method 1004 |
| Environmental | Vibration | MIL-STD-883, Method 2007, Condition A |
| Environmental | Resistance to soldering heat | J-STD-020C Table 5-2 Pb-free devices (2 cycles max) |



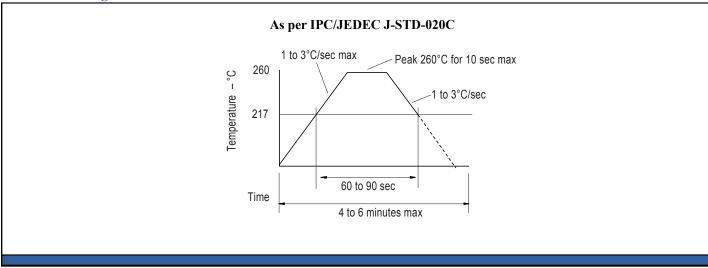
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3.3V CMOS Low Jitter, High Frequency Crystal Clock Oscillator (XO)



Reflow Soldering Profile



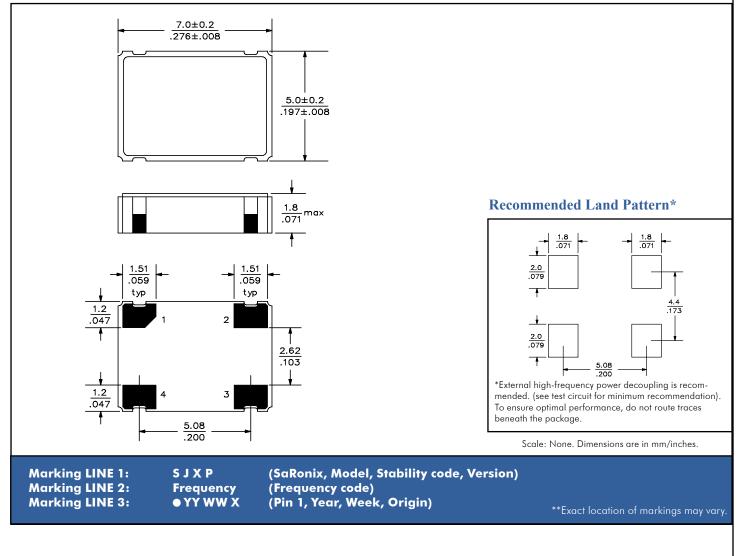
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3.3V CMOS Low Jitter, High Frequency Crystal Clock Oscillator (XO)

Mechanical Drawings



All specifications are subject to change without notice. DS 263 Rev B | 08/19/05

